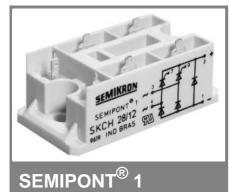
# **SKCH 28**



### **Controllable Bridge** Rectifiers

#### **SKCH 28**

#### **Features**

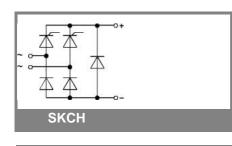
- Sturdy isolated metal baseplate
- · Fast-on terminals with solder tips
- Suitable for wave soldering
- · High surge current rating
- UL recognized, file no. E 63 532

### **Typical Applications**

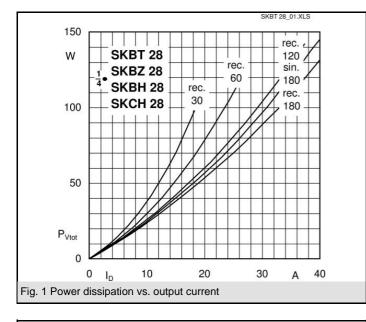
- Controllable single phase rectifierDC power supplies
- DC motor controllers
- DC motor field controllers
- 1) Painted metal shield of minimum 250 x 250 x 1 mm: R<sub>th(c-a)</sub> = 1,85 K/W
- 2) Freely suspended or mounted on insulator

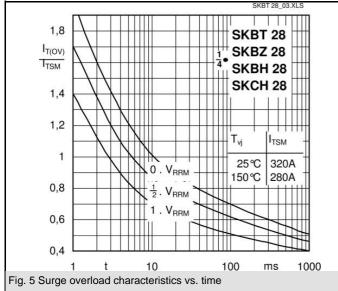
V <sub>RSM</sub>	V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>D</sub> = 28 A (full conduction)
V	V	(T <sub>c</sub> = 89 °C)
400	400	SKCH 28/04
600	600	SKCH 28/06
800	800	SKCH 28/08
1200	1200	SKCH 28/12
1400	1400	SKCH 28/14

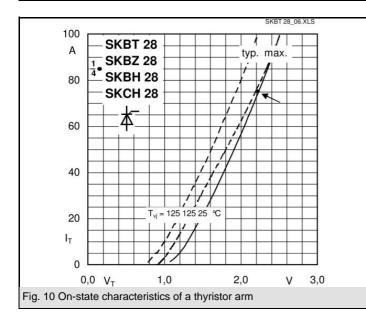
Symbol	Conditions	Values	Units
I <sub>D</sub>	T <sub>c</sub> = 85 °C	30	А
	$T_a = 45 \text{ °C}; \text{ chassis } ^{1)}$	13	А
	T <sub>a</sub> = 45 °C; P5A/100	15	А
	T <sub>a</sub> = 45 °C; P13A/125	16	А
	T <sub>a</sub> = 45 °C; P1A/120	23	А
I <sub>TSM</sub> , I <sub>FSM</sub>	T <sub>vi</sub> = 25 °C; 10 ms	320	А
	T <sub>vi</sub> = 125 °C; 10 ms	280	А
i²t	T <sub>vi</sub> = 25 °C; 8,3 10 ms	510	A²s
	T <sub>vj</sub> = 125 °C; 8,3 10 ms	390	A²s
V <sub>T</sub>	T <sub>vi</sub> = 25 °C; I <sub>T</sub> =75 A	max. 2,25	V
V <sub>T(TO)</sub>	$T_{vi} = 125 \text{ °C};$	1	V
r <sub>T</sub>	T <sub>vi</sub> = 125 °C	16	mΩ
I <sub>DD</sub> ; I <sub>RD</sub>	$T_{vj}^{i}$ = 125 °C; $V_{DD}$ = $V_{DRM}$ ; $V_{RD}$ = $V_{RRM}$	max. 8	mA
t <sub>gd</sub>	$T_{vi} = 25 \text{ °C}; I_G = 1 \text{ A}; di_G/dt = 1 \text{ A}/\mu\text{s}$	1	μs
t <sub>gr</sub>	$V_{\rm D} = 0.67 \cdot V_{\rm DRM}$	1	μs
(dv/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C	max. 500	V/µs
(di/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C; f = 50 Hz	max. 50	A/µs
t <sub>q</sub>	$T_{vi}^{(1)} = 125 \text{ °C; typ.}$	80	μs
I <sub>H</sub>	$T_{vi}^{,j}$ = 25 °C; typ. / max.	50 / 150	mA
IL .	$T_{vi} = 25$ °C; R <sub>G</sub> = 33 Ω	100 / 300	mA
V <sub>GT</sub>	$T_{vi} = 25 ^{\circ}C;  d.c.$	min. 2	V
I <sub>GT</sub>	$T_{vi}^{vj} = 25 \text{ °C; d.c.}$	min. 100	mA
V <sub>GD</sub>	$T_{vi}^{vj} = 125 \text{ °C; d.c.}$	max. 0,25	V
I <sub>GD</sub>	T <sub>vi</sub> = 125 °C; d.c.	max. 3	mA
R <sub>th(j-c)</sub>	per thyristor / diode	1,8	K/W
ui(j=c)	total	0,45	K/W
R <sub>th(c-s)</sub>	total	0,1	K/W
R <sub>th(j-a)</sub>	total <sup>2)</sup>	15	K/W
T <sub>vi</sub>		- 40 + 125	°C
T <sub>stg</sub>		- 40 + 125	°C
V <sub>isol</sub>	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 ( 3000 )	V
M <sub>s</sub>	case to heatsink	2	Nm
M <sub>t</sub>		n.a.	Nm
m		66	g
Case	SKCH	G 25	

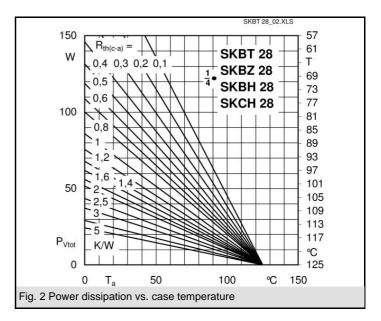


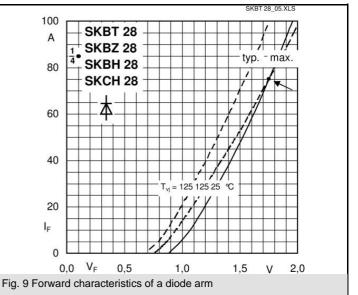
### **SKCH 28**

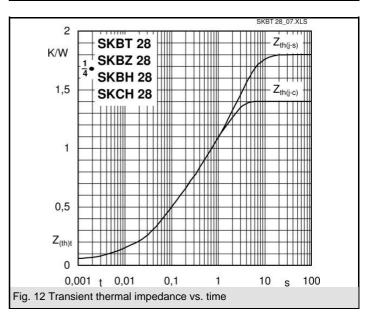




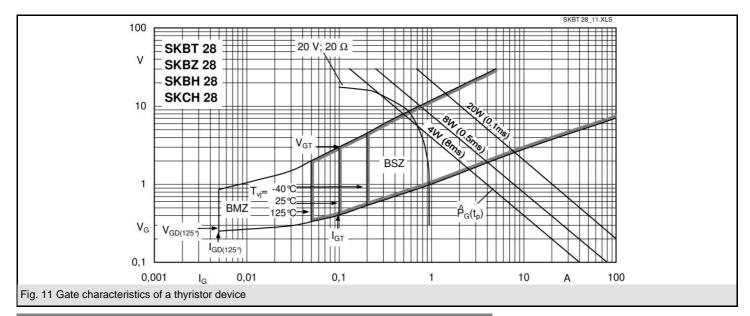


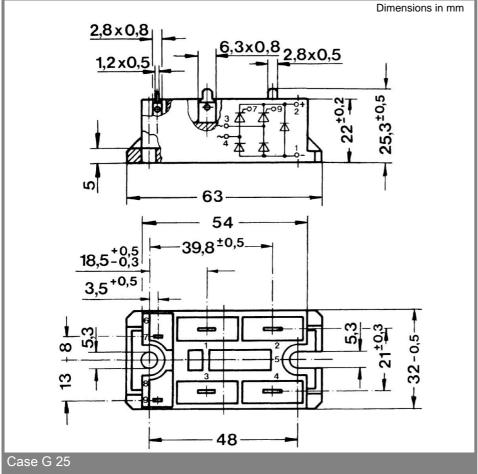






## **SKCH 28**





This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.